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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Pary Baluswamy et al.

Patent No.: 6,914,017

Issue Date: July 5, 2005

Title: RESIDUE FREE OVERLAY TARGET

Examiner: Marcos D Pizarro Crespo

Group Art Unit: 2814

Docket No: 2269-4307US

Commissioner for Patents
Office of Patent Publication
ATTN: Certificate of Correction Branch

We are transmitting herewith the attached:

- Request for Certificate of Correction.
 Certificate of Correction Form - PTO-1050 (in duplicate)
 A return postcard.

Please charge any additional fees or credit overpayment to Deposit Account No. 13-3092.

Customer Number: 26809

Respectfully submitted,

By: 
Russ Sliter
Reg. No. 39,838

Date: January 11, 2008

*Certificate
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of Correction*

Christine Hartness

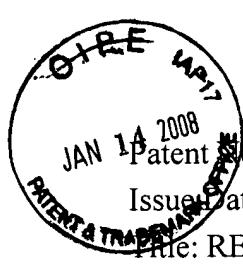
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Patent No.: 6,914,017

Docket No: 2269-4307US

Issue Date: July 5, 2005

Patentee: Pary Baluswamy et al.

Title: RESIDUE FREE OVERLAY TARGET

REQUEST FOR CERTIFICATION OF CORRECTION

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450
ATTN: Certificate of Correction Branch

It is requested that a Certificate of Correction be issued correcting printing errors appearing in the above-identified United States patent. Two copies of the text of the Certificate in the suggested form are enclosed.

As the error is that of the Patent Office, it is believed that no fee is due.

Issuance of the Certificate of Correction would neither expand nor contract the scope of the claims as properly allowed, and re-examination is not required.

Respectfully submitted,

Customer Number: 26809

Date: January 11, 2008

By:


Russ Sliter
Reg. No. 39,838



Christine Harness

Name



Signature

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UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO : 6,914,017

Page (1) of 1

DATED : July 5, 2005

INVENTOR(S) : Baluswamy et al.

It is certified that errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the face page, in field (54), in "Title", in column 1, line 1, delete "RESIDUE FREE OVERLAY TARGET" and insert - - RAISED-LINES OVERLAY SEMICONDUCTOR TARGETS AND METHOD OF MAKING THE SAME - -, therefor.

On the face page, in field (56), under "U.S. Patent Documents", in column 1, line 5, below "5,786,260 A 7/1998 Jang et al." insert - - 5,841,144 11/1998 Cresswell - -.

On the face page, in field (57), under "Abstract", in column 2, line 2, delete "residue-residue free" and insert - - residue free - -, therefor.

On the face page, in field (57), under "Abstract", in column 2, line 8, delete "layers," and insert - - layers - -, therefor.

In column 1, line 1, delete "RESIDUE FREE OVERLAY TARGET" and insert - - RAISED-LINES OVERLAY SEMICONDUCTOR TARGETS AND METHOD OF MAKING THE SAME - -, therefor.

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